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Vishay Siliconix

# Automotive P-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY			
V <sub>DS</sub> (V)	-40		
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0250		
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0360		
I <sub>D</sub> (A)	-24		
Configuration	Single		
Package	PowerPAK SO-8L		

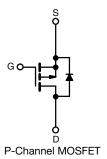
#### **FEATURES**

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V <sub>DS</sub>	-40	V	
Gate-source voltage		$V_{GS}$	± 20	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	
Continuous drain current	T <sub>C</sub> = 25 °C	I-	-24		
	T <sub>C</sub> = 125 °C	I <sub>D</sub>	-14		
Continuous source current (diode conduction)		I <sub>S</sub>	-25	А	
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	-75		
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	-20		
Single pulse avalanche energy	L=0.1111H	E <sub>AS</sub>	20	mJ	
Maximum power dissipation	T <sub>C</sub> = 25 °C	D	27	W	
	T <sub>C</sub> = 125 °C	$P_D$	9	VV	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +175	°C	
Soldering recommendations (peak temperature) <sup>c</sup>		-	260		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction to ambient	PCB mount b	$R_{thJA}$	70	°C/W	
Junction to case (drain)			5.5	C/VV	

#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu\text{s},$  duty cycle  $\leq 2~\%$
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (<a href="www.vishay.com/doc?73257">www.vishay.com/doc?73257</a>). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection



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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							•	
Drain-source breakdown voltage	$V_{DS}$	$V_{GS} = 0$ , $I_D = -250 \mu A$		-40	-	-	V	
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	$V_{DS} = V_{GS}, I_D = -250 \mu\text{A}$		-2.0	-2.5		
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> =	0 V, V <sub>GS</sub> = ± 20 V	-	-	± 100	nA	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = -40 V	-	-	-10		
		V <sub>GS</sub> = 0 V	$V_{DS} = -40 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μA	
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = -40 V, T <sub>J</sub> = 175 °C	-	-	-150		
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = -10 V	$V_{DS} \le -5 \text{ V}$	-40	-	-	Α	
Drain-source on-state resistance <sup>a</sup>		V <sub>GS</sub> = -10 V	I <sub>D</sub> = -18 A	-	0.0165	0.0250		
	Б	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -18 A, T <sub>J</sub> = 125 °C	-	-	0.0400		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = -10 V	I <sub>D</sub> = -18 A, T <sub>J</sub> = 175 °C	-	-	0.0486	Ω	
		$V_{GS} = -4.5 \text{ V}$	I <sub>D</sub> = -15 A	-	0.0255	0.0360		
Forward transconductance b	9fs	V <sub>DS</sub> =	= -15 V, I <sub>D</sub> = -18 A	-	37	-	S	
Dynamic <sup>b</sup>								
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = -20 V, f = 1 MHz	-	2436	3415	pF	
Output capacitance	Coss	V <sub>GS</sub> = 0 V		-	170	240		
Reverse transfer capacitance	C <sub>rss</sub>			-	158	225		
Total gate charge <sup>c</sup>	Qg		V <sub>DS</sub> = -20 V, I <sub>D</sub> = -7.5 A	-	46	70	nC	
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	V <sub>GS</sub> = -10 V		-	8.6	-		
Gate-drain charge <sup>c</sup>	$Q_{gd}$			-	8.1	-		
Gate resistance	R <sub>g</sub>	f = 1 MHz		1.6	3.4	5.1	Ω	
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>				13	20		
Rise time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = -20 \text{ V}, \text{ R}_{L} = -2.67 \Omega,$ $I_{D} \cong -1 \text{ A}, \text{ V}_{GEN} = -10 \text{ V}, \text{ R}_{g} = 1 \Omega$		-	3	6	ns	
Turn-off delay time c	t <sub>d(off)</sub>			-	46	70		
Fall time <sup>c</sup>	t <sub>f</sub>			-	8	12		
Source-Drain Diode Ratings and Character	eristics <sup>b</sup>				•			
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	-75	Α	
Forward voltage	V <sub>SD</sub>	$I_F = -5 \text{ A}, V_{GS} = 0$		-	-0.81	-1.2	V	
Body diode reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> = -4.5 A, di/dt = 100 A/μs		-	18	36	ns	
Body diode reverse recovery charge	Q <sub>rr</sub>			-	13	26	nC	
Reverse recovery fall time	ta			-	11	-		
Reverse recovery rise time	t <sub>b</sub>			-	7	-	ns	
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	-1.5	-	Α	

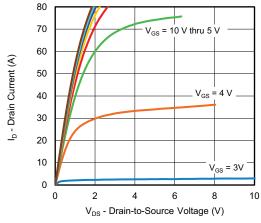
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

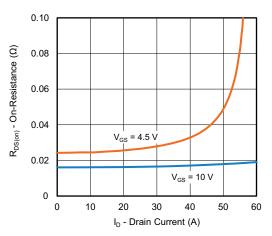
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



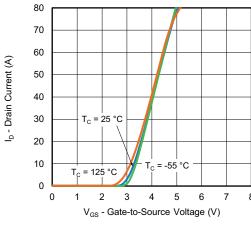
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



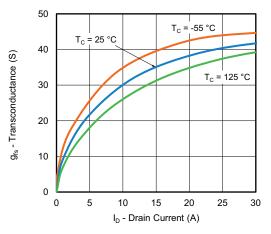




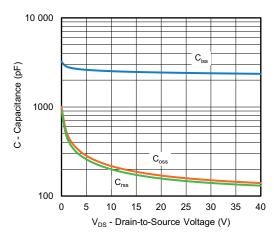
On-Resistance vs. Drain Current



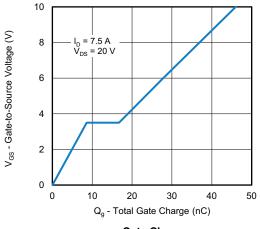
**Transfer Characteristics** 



Transconductance



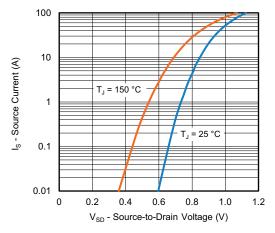
Capacitance



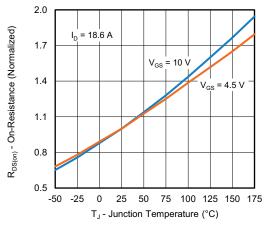
**Gate Charge** 



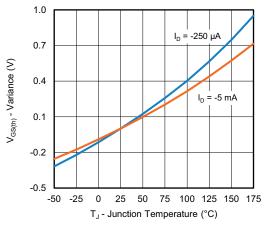
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



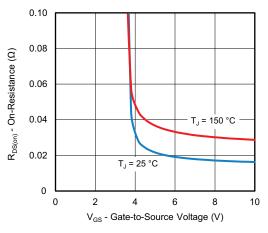
#### **Source Drain Diode Forward Voltage**



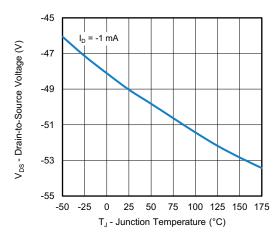
**Threshold Voltage** 



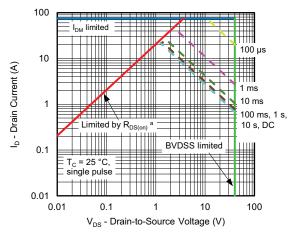
On-Resistance vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage



**Drain Source Breakdown vs. Junction Temperature** 



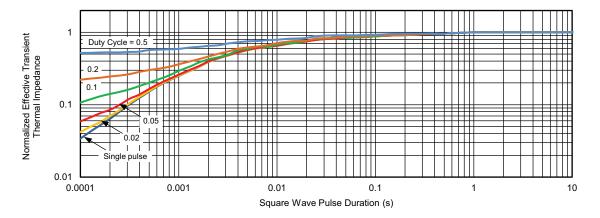
Safe Operating Area

#### Note

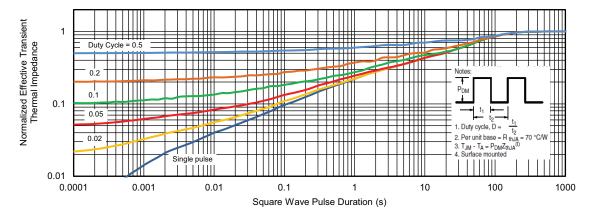
a.  $V_{GS} > minimum \ V_{GS}$  at which  $R_{DS(on)}$  is specified



### **THERMAL RATINGS** (T<sub>C</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Case



#### Normalized Thermal Transient Impedance, Junction-to-Ambient

#### Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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